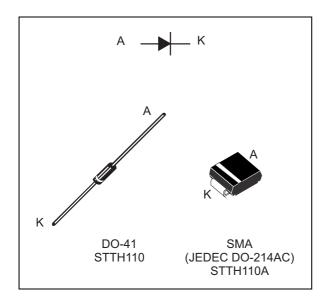


High voltage ultrafast rectifier

Datasheet - production data



Description

The STTH110, which is using ST ultrafast high voltage planar technology, is especially suited for free-wheeling, clamping, snubbering, demagnetization in power supplies and other power switching applications.

Table 1. Device summary

Symbol	Value
I _{F(AV)}	1 A
V_{RRM}	1000 V
T _{j (max)}	175 °C
V _{F (max)}	1.42 V

Features

- Low forwarded voltage drop
- · High reliability
- · High surge current capability
- Soft switching for reduced EMI disturbances
- Planar technology

Characteristics STTH110

1 Characteristics

Table 2. Absolute ratings (limiting values at T_i = 25 °C, unless otherwise specified)

Symbol		Value	Unit				
V _{RRM}	Repetitive peak reverse v	Repetitive peak reverse voltage					
V _(RMS)	Voltage rms				700	V	
	Average for word according	SMA	T _L = 110 °C	_L = 110 °C δ = 0.5		Λ	
I _{F(AV)}	Average forward current	DO-41	$T_L = 125 ^{\circ}\text{C} \delta = 0.5$		1	Α	
	Forward Surge current t = 8.3 ms			SMA	18	Α	
IFSM				DO-41	20	A	
T _{stg}	Storage temperature rang	-50 to + 175	°C				
Tj	Maximum operating juncti	Maximum operating junction temperature			175	°C	

Table 3. Thermal resistance

Symbol		Parameter				
D	Junction to lead		SMA	30		
R _{th(j-l)}	Junction to lead	Lead length = 10 mm	DO-41	45	°C/W	
R _{th(j-a)}	Junction to ambient	Lead length = 10 mm	DO-41	110		

Table 4. Static electrical characteristics

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
	Reverse leakage current	T _j = 25 °C	V _R = 1000 V			10	^
I _R	Reverse leakage current	T _j = 125 °C	v _R = 1000 v			50	μΑ
V _F	Forward voltage drop	T _j = 25 °C	Ι – 1 Λ			1.7	V
∀ F	V _F Forward voltage drop	T _j = 150 °C	I _F = 1 A		0.98	1.42	V

To evaluate the conduction losses use the following equation:

$$P = 1.20 \text{ x } I_{F(AV)} + 0.225 I_{F^2(RMS)}$$

Table 5. Dynamic electrical characteristics

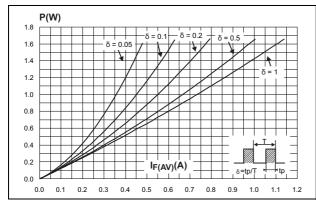
Symbol	Parameter	Tests conditions			Тур.	Max.	Unit
t _{rr}	Reverse recovery time	T _j = 25 °C	$I_F = 0.5, A$ $I_{rr} = 0.25 A,$ $I_R = 1 A$			75	ns
t _{fr}	Forward recovery time		I _F = 1 A,			300	ns
V _{FP}	Forward recovery voltage	T _j = 25 °C	$I_F = 1 A,$ $dI_F/dt = 50 A/ms$ $V_{FR} = 1.1 x V_F max$			18	V



STTH110 Characteristics

Figure 1. Conduction losses versus average current

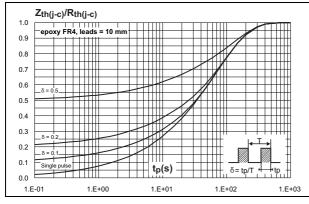
Figure 2. Forward voltage drop versus forward current (typical values)



10.0 T_{=150°C} (ypical values) T_{=25°C} (maximum values) T_{=25°C} (max

Figure 3. Relative variation of thermal impedance junction ambient versus pulse duration (DO-41)

Figure 4. Relative variation of thermal impedance junction ambient versus pulse duration (SMA)



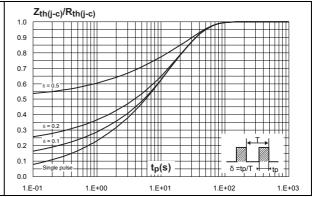
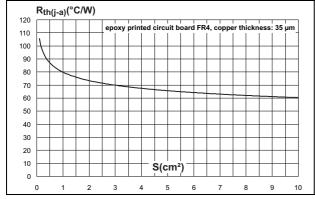
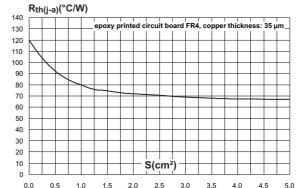


Figure 5. Thermal resistance junction to ambient versus copper surface under each lead (DO-41) Figure 6. Thermal resistance junction to ambient versus copper surface under each lead (SMA)





Package information STTH110

2 Package information

- Epoxy meets UL94,V0
- Lead-free package
- Band indicates cathode
- Bending method (DO-41): see Application note AN1471

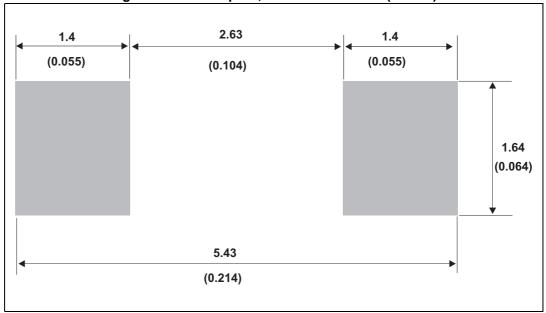
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Figure 7. SMA dimensions definitions

Table 6. SMA dimension values

	Dimensions						
Ref.		Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
A1	1.90		2.45	0.075		0.094	
A2	0.05		0.20	0.002		0.008	
b	1.25		1.65	0.049		0.065	
С	0.15		0.40	0.006		0.016	
D	2.25		2.90	0.089		0.114	
Е	4.80		5.35	0.189		0.211	
E1	3.95		4.60	0.156		0.181	
L	0.75		1.50	0.030		0.059	

Figure 8. SMA footprint, dimensions in mm (inches)



Package information STTH110

C A C ØB

Figure 9. DO-41 (plastic) dimensions definitions

Table 7. DO-41 (plastic) dimension values

	Dimensions						
Ref.	Millimeters				Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	4.07		5.20	0.160		0.205	
В	2.04		2.71	0.080		0.107	
С	25.4			1			
D	0.71		0.86	0.028		0.034	

3 Ordering information

Table 8. Ordering information

Order codes	Marking	Package	Weight	Base qty	Delivery mode
STTH110	STTH110	DO-41	0.34 g	2000	Ammopack
STTH110A	H10	SMA	0.068 g	5000	Tape and reel 13"
STTH110RL	STTH110	DO-41	0,34 g	5000	Tape and reel 13"

4 Revision history

Table 9. Document revision history

Date	Revision	Changes
Jan-2003	1	Initial release.
30-Sept-2009	2	Updated Table 8.
20-Dec-2013	3	Updated Table 4.

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